



Fast Recovery Epitaxial Diode (FRED)

preliminary data

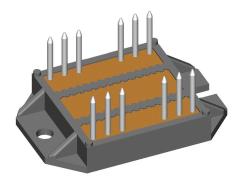
 $I_{FAVM} = 2x 147 A$

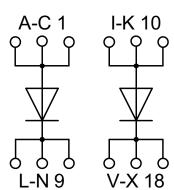
 $V_{RRM} = 600 V$

 $t_{m} = 35 \text{ ns}$

Part number

DSEI2x161-06P





Features / Advantages:

- 2 independent FRED in 1 package
- · Planar passivated chips
- · Very short recovery time
- · Leads suitable for PC board soldering
- Very short recovery time
- · Soft recovery behaviour
- · Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- · Small and light weight

Applications:

- Antiparallel diode for high frequency switching devices
- · Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- · Ultrasonic cleaners and welders

Package: ECO-PAC2

- Isolation voltage: 3000 V~
- · Industry standard outline
- · RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- · Reduced weight
- Advanced power cycling

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.





preliminary data

Diode	e				Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.		
I _{FRMS}	RMS forward current		$T_{VJ} = T_{VJM}$			270	А	
I _{FAVM} ①	max. average forward current	rectangular, d = 0.5	T _C = 70°C			147	Α	
FSM	max. surge forward current	t = 10 ms (50 Hz), sine $t = 8.3 ms$ (60 Hz), sine	$T_{VJ} = 45^{\circ}C$			1200 1300	A A	
		t = 10 ms (50 Hz), sine $t = 8.3 ms$ (60 Hz), sine	$T_{VJ} = 150^{\circ}C$			1080 1170	A A	
l²t	Pt value for fusing	t = 10 ms (50 Hz), sine $t = 8.3 ms$ (60 Hz), sine	$T_{VJ} = 45^{\circ}C$			7200 7100	A ² s A ² s	
		t = 10 ms (50 Hz), sine $t = 8.3 ms$ (60 Hz), sine	$T_{VJ} = 150^{\circ}C$			5800 5700	A²s A²s	
I _R	reverse current	$V_R = V_{RRM}$ $V_R = 0.8 \cdot V_{RRM}$ $V_R = 0.8 \cdot V_{RRM}$	$T_{VJ} = 25^{\circ}C$ $T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$			12 3 80	mA mA mA	
V _F	forward voltage	I _F = 200 A	T _{VJ} = 25°C			1.45	V	
V _{TO}	threshold voltage slope resistance	for power-loss calculations only $T_{VJ} = T_{VJM}$				0.85 2.7	V mΩ	
R _{thJC}	thermal resistance junction to case thermal resistance junction to heatsink				0.20	0.29	K/W K/W	
I _{RM}	max. reverse recovery current	$I_F = 100 \text{ A}; -di_F/dt = 200 \text{ A/}\mu\text{s}$ $T_{VJ} = 100^{\circ}\text{C}$ $V_R = 100 \text{ V}; L \le 0.05 \mu\text{H}$			45		Α	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; -di/dt = 400 \text{ A/}\mu\text{s}; V_R = 30 \text{ V}$	$T_{VJ} = 25^{\circ}C$		35		ns	

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , V_{R} = 0.8 V_{RRM} , duty cycle d = 0.5





preliminary data

Package	ECO-PAC2			Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.	
I _{RMS}	RMS current	nt per terminal				100	Α
T _{VJ} T _{op} T _{stg}	virtual junction temperature operation temperature storage temperature		-40 -40 -40		150 125 125	°C °C °C	
Weight					24		g
M _D	mounting torque			1.4		2.0	Nm
d _{Spp/App}	creepage distance on surface striking distance through air		terminal to terminal terminal to backside	6.0 10.0			mm mm
V _{ISOL}	isolation voltage	t = 1 second t = 1 minute 50/60 Hz, RM	S; I _{ISOL} ≤ 1 mA	3000 2500			V

